Fig. 1

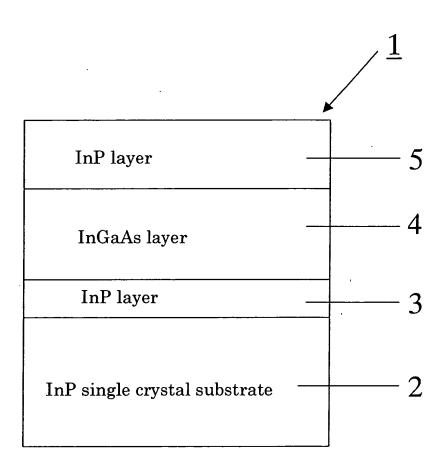
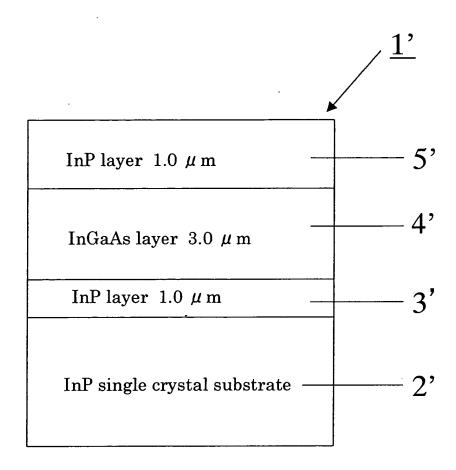
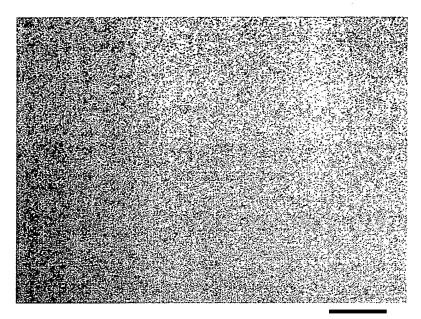


Fig. 2



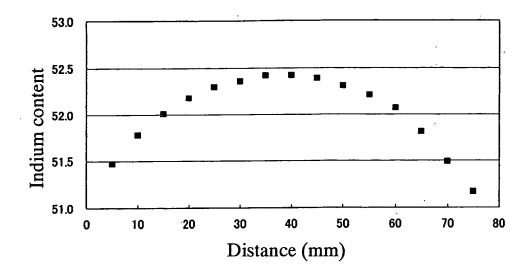
371 Patent Application
In re Kenji KOHIRO et al. Filed: May 10, 2006
METHOD FOR MANUFACTURING COMPOUND
SEMICONDUCTOR EXPITAXIAL SUBSTRATE
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Fig. 3



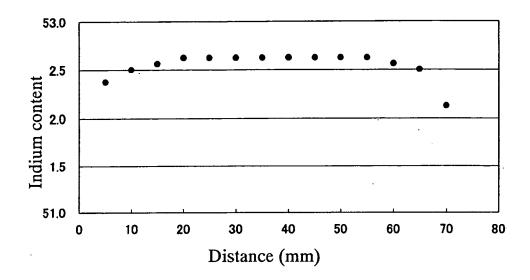
200 μ m

Fig. 4



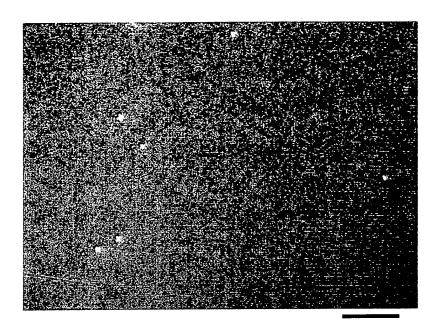
371 Patent Application
In re Kenji KOHIRO et al. Filed: May 10, 2006
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Fig. 5



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Fig. 6



 $200\,\mu$  m

Fig. 7

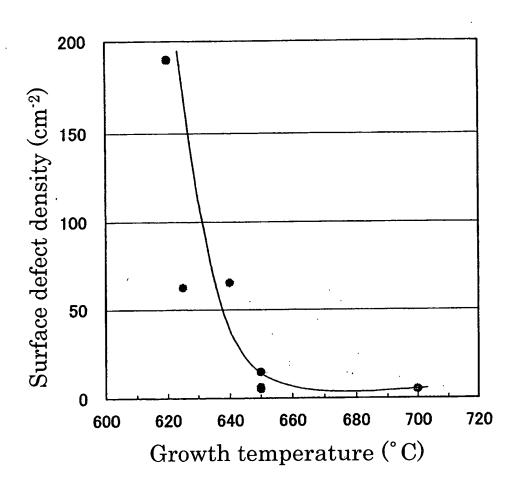
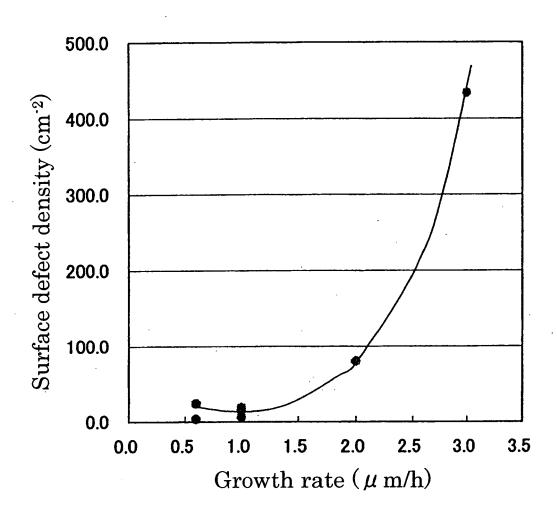


Fig. 8



A SECULIAR S

Fig. 9

